Relaxation of Energy and Momentum in an Carrier-Phonon System

A. Rossani
Department of Applied Science and Technology, Politecnico di Torino, Corso Duca degli Abruzzi, Torino, Italy
Email: alberto.rossani@polito.it

Received June 25, 2012; revised July 19, 2012; accepted August 1, 2012

ABSTRACT

If electrons (e) and holes (h) in metals or semiconductors are heated to the temperatures Te and Th greater than the lattice temperature Tp, the electron-phonon interaction causes energy relaxation. In the non-uniform case a momentum relaxation occurs as well. In view of such an application, a new model, based on an asymptotic procedure for solving the generalized kinetic equations of carriers and phonons is proposed, which gives naturally the displaced Maxwellian at the leading order. After that, balance equations for the electron number, hole number, energy densities, and momentum densities are constructed, which constitute now a system of five equations for the electron chemical potential, the temperatures and the drift velocities. In the drift-diffusion approximation the constitutive laws are derived and the Onsager relations recovered.

Keywords: Energy; Momentum

1. Introduction

In semiconductor modeling three approaches are widely applied, according to the Physical situation we deal with. The microscopic approach is based on Monte Carlo simulations which can account for as many aspects of semiconductor Physics as we want. Nevertheless it is well known that these simulations are time consuming and therefore expensive.

The mesoscopic approach is based on the Boltzmann transport equation (BTE). Several numerical techniques are developed in order to face a numerical solution of the problem. The distribution function depends on seven variables (momentum, position, time) so that the task is quite formidable.

The macroscopic approaches are based on the weak form of the BTE, which give rise to a hierarchy of coupled equations for the moments of the distribution function. Such approach requires a truncation at some order based on closure assumptions for the higher order fluxes and for the production terms for non-conservation equations.

Most of the semiconductor macroscopic models have in common the assumption, at the basis of the closure approximation, that some higher moments can be calculated by utilizing a displaced Maxwellian. This approach would be justified if one had a systematic approximation for solving the Boltzmann transport equations, asymptotic with respect to some parameters, whose leading terms would be displaced Maxwellians. Such an approach is now available and the present model can be viewed as an improvement of a previous paper [1] on this topic, by considering a two-fluid description of the electron-phonon system which occurs.

On the other hand, as pointed out in ref. [2], fractal or power law distribution functions are of interest in solid state Physics. An example, given in ref. [2], is the thermalization, due to the electron-phonon interactions, of a non-equilibrium electron-phonon system which occurs if electrons and holes in metals or semiconductors are heated to a temperature Te greater than the lattice temperature Tp. In the non-uniform case a momentum relaxation occurs as well.

In view of such an application we consider a generalized kinetic theory of carriers and phonons (GKTCP), recently proposed [3], which accounts for non-Gibbsian statistics.

We start from the generalized Bloch-Boltzmann-Peierls coupled equations for the distribution functions of electrons and phonons.

After that, by means of an expansion of both the unknowns and the interaction kernels with respect to a small parameter which accounts for the umklapp processes (with no momentum conservation), the lowest order equations show that the displaced Maxwellian approximation is justified. A closed set of two-fluid equations for the chemical potential of electrons, the temperatures, and the drift velocities can be constructed, which recalls
the extended thermodynamics model [4].

In the drift-diffusion approximation the constitutive equations can be written and the Onsager symmetry relations are recovered.

We stress that in the present model

1) The displaced Maxwellian approximation is not an *ad hoc* assumption but is justified by the expansion we apply.

2) The statistics of both electrons, holes and phonons is left general, in order to account for non-standard cases.

3) Phonons are treated as a participating species, which brings energy and momentum.

4) The correct phonon-phonon, electron-phonon, electron-electron, hole-phonon, and hole-hole interaction kernels are utilized: we avoid the use of relaxation time approximations.

The most qualifying point is (3). In fact the usual assumption that the phonon field can be treated as a fixed background is dropped here, since “any thermal gradient give rise to transport of heat by the phonons, whilst an electric current, though carried by electrons, cannot fail to transfer some of its momentum to the lattice vibrations, and drag them along with it” (Ziman). Finally we can say that the present model can be seen as generalization of previous ones like [5], by means of the treatment of phonons.

2. The GKTCP Equations

Consider three interacting populations: electrons (e), with charge-\(e\), holes (h), with charge \(e\), and phonons (p). Let \(N_g(k_x,t)\) be the distribution function of phonons (quasi-momentum \(k\), energy \(\epsilon_g(k)\) of type \(g\) (i.e. branch \(g\) of the phonon spectrum) \(n^{pe}_g = n^{he}_g(P_x,t)\) the distribution function of electrons (quasi-momentum \(P\), energy \(\epsilon_p\)), and \(n^{ph}_g = n^{hp}_g(P_x,t)\) the distribution function of holes (quasi-momentum \(P\), energy \(\epsilon_h\)). The GKTCP equations read

\[
\mathcal{D}_g N_g = \left( \frac{\partial N_g}{\partial t} \right)_{pp} + \left( \frac{\partial N_g}{\partial t} \right)_{pe} + \left( \frac{\partial N_g}{\partial t} \right)_{ph},
\]

\[
\mathcal{D}_p N_p = \left( \frac{\partial n_p}{\partial t} \right)_{sp} + \left( \frac{\partial n_p}{\partial t} \right)_{ap},
\]

where \(\mathcal{D}_g\) is the electric potential. Observe that, since \(\epsilon_g\) and \(\epsilon_p\) are even, \(u_g\) and \(v_p\) are odd.

Moreover

\[
\left( \frac{\partial N_g}{\partial t} \right)_{pp} = 2 \int \frac{\omega_{pp}(P \to P', k) (\phi^{pe}_g \Psi' g - \Psi' g \phi^{pe}_g)}{8\pi^3} dP',
\]

where \(P' = P - k + b(P \to P', k)\), is the difference between the number of phonons \(k\) emitted by electrons with any quasimomenta \(P\) and the number of phonons absorbed by electrons with any \(P\)!

For electrons we have

\[
\mu = \int \frac{\omega_{pp}(P \to P', k) (\phi^{pe}_g \Psi' g - \Psi' g \phi^{pe}_g)}{8\pi^3} dP',
\]

\[
\mathcal{P} = \int \frac{\omega_{pp}(P \to P', k) (\phi^{pe}_g \Psi' g - \Psi' g \phi^{pe}_g)}{8\pi^3} dP',
\]
The first term corresponds to processes with emission of a phonon having quasimomentum \( k \) by an electron having a given quasimomentum \( P \) and reverse processes. The second term corresponds to processes with absorption of a phonon by an electron with quasimomentum \( P \) and reverse processes.

The \( \omega \)'s are transition probabilities which account for energy conservation and satisfy the following symmetry relations:

\[
\omega_{pp}(P \to P', k) = \omega_{pp}(P \to P, k) = \omega_{pp}(P', k \to P).
\]

Moreover, the e-e collision integral reads

\[
\left( \frac{\partial n_e}{\partial t} \right)_{ap} = \iint \omega_{ae}(P, P_1 \to P', P'_1) \left( \psi_{P_1 b}^* \psi_{P'_1 b} e_F \phi_{P'_1 h} e_F - \psi_{P b}^* \psi_{P h} \phi_{P h} e_F \right) \frac{dP dp P'}{64\pi^6}.
\]

For holes we have

\[
\left( \frac{\partial n_p}{\partial t} \right)_{hp} = \sum_{g} \iint \omega_{hg}(P', k \to P) \left( \phi_{p g}^* \psi_{P_1 b} b_F - \phi_{p g} \psi_{P b} b_F \right) + \omega_{hp}(P' \to P, k) \left( \phi_{p g}^* \psi_{P_1 b} b_F - \phi_{p g} \psi_{P b} b_F \right) \frac{dP dp P'}{8\pi^6},
\]

where

\[
P' = P - k + b(P', k \to P),
P'' = P + k + b(P'' \to P, k).
\]

The first term corresponds to processes with emission of a phonon having quasimomentum \( k \) by a hole having a given quasimomentum \( P \) and reverse processes. The second term corresponds to processes with absorption of a phonon by a hole with quasimomentum \( P \) and reverse processes.

The \( \omega \)'s are transition probabilities which account for energy conservation and satisfy the following symmetry relations:

\[
\omega_{ph}(P \to P', k) = \omega_{hp}(P \to P', k) = \omega_{ph}(P', k \to P).
\]

Moreover, the h-h collision integral reads

\[
\left( \frac{\partial n_h}{\partial t} \right)_{ah} = \iint \omega_{ah}(P_1, P \to P_1', P') \left( \psi_{P_1 b}^* \psi_{P'_1 b} e_F \phi_{P'_1 h} e_F - \psi_{P b}^* \psi_{P h} \phi_{P h} e_F \right) \frac{dP dp P'}{64\pi^6}.
\]

### 3. Asymptotic Expansion and Balance Equations

By following [1] we expand the kernels and the unknowns with respect to a small parameter \( \epsilon \) which takes into account the effect of the umklapp (U) processes in addition to the normal (N) ones (which conserve momentum). We start with carriers (the extension to phonons is trivial). The sought expansions for \( n_e^a \) and \( N_g \)

\[
n_e^a = n_e^N + \epsilon n_e^U, \quad N_g = N_g^N + \epsilon N_g^U.
\]

Accordingly

\[
\left( \frac{\partial n_e^a}{\partial t} \right)_{ap} = \left( \frac{\partial n_e^N}{\partial t} \right)_{ap} + \epsilon \left( \frac{\partial n_e^U}{\partial t} \right)_{ap} + \left( \frac{\partial n_e^N}{\partial t} \right)_{a a}
\]

\[
+ \epsilon \left( \frac{\partial n_e^U}{\partial t} \right)_{a a},
\]

where \( \omega_{ap} \) and \( \omega_{aa} \)

\[
\omega_{ap} = \omega_{ap}^N + \epsilon \omega_{ap}^U, \quad \omega_{aa} = \left( \frac{1}{\epsilon} \right) \omega_{ap}^N + \omega_{ap}^U.
\]

Observe that the expansion of \( \omega_{ap} \) is singular, since the relaxation due to e-e interactions is considered quicker with respect to the case of the e-p ones [6].

We can write now...
The equations of order –1 for both phonons and electrons are solved (see appendix) by
\[
\ln \left( \frac{\Phi_N}{\Psi_N} \right) = \left( \frac{V_p \cdot k - \omega_e}{T_p} \right), \quad \ln \left( \frac{\Phi_{Np}}{\Psi_{Np}} \right) = \left( \frac{\mu_a + V_p \cdot p - \omega^*_{e}}{T_a} \right)
\]
where \( T_p = T_a(x,t) \) are the absolute temperatures while \( \mu_a = \mu_a(x,t) \) is the chemical potential of the electron gas (the meaning of \( V_a \) is discussed later). Thus, at the leading order of this expansion, we find the drifted (generalized) Bose-Einstein (BE) and Fermi-Dirac (FD) distribution functions. Let us define the functions \( B \) and \( F_a \) as follows:
\[
N^*_g = B(V_p, \omega_e - V_p \cdot k),
\]
\[
n^{*}_{Np} = F_a[\mu_a - V_a \cdot p - \omega^*_{e}],
\]
where \( B_a = 1/T_a \). In the non-generalized case we have
\[
B(\omega_e) = 1/(e^{\omega_e} - 1), \quad F_a(\omega_e) = 1/(e^{\omega_e} + 1),
\]
that is the BE and FD distribution functions are recovered. Usually \( N^*_g \) and \( n^{*}_{Np} \) are factored into two components, a symmetric component \( 0 \) which is even in momentum and an anti-symmetric component \( 1 \)
\[
\frac{\partial N^*_g}{\partial t} = \beta_p V_p \cdot \left( \left[ \frac{1}{2} \sum_{g \neq 0} \Psi_0^0 \Phi_0^0 \Phi_{g,0}^0 \omega_{pp}'(k_1, k_2 \rightarrow k) (k_2 + k_1 - k) + \sum_{g \neq 0} \Psi_0^0 \Phi_0^0 \Phi_{g,0}^0 \omega_{pp}'(k_1, k_2 \rightarrow k _3) (-k_3 + k_1 + k) \right] \frac{dk_3}{8\pi}\right)\]
\[
\frac{\partial n^{*}_{Np}}{\partial t} = \beta_a V_a \cdot \int \omega_{pp}'(P, P_1 \rightarrow P', P'_1) \Psi_{Np}^{*} \Psi_{Np}^{*} \frac{dP, dP'}{64\pi^2}
\]
Finally
\[
\frac{\partial N^*_g}{\partial t} = \left[ \frac{1}{2} \sum_{g \neq 0} \omega_{pp}(P' \rightarrow P) \Psi_{Np}^{*} \Phi_{g,0}^0 \Phi_{g,0}^0 \Psi_N^0 \right] \frac{dP}{8\pi^2}
\]
and, in the linear non-equilibrium thermodynamic approach,
\[
\frac{\partial N^*_g}{\partial t} = 2 \sum_{g \neq 0} \omega_{pp}(P' \rightarrow P) \Psi_{Np}^{*} \Phi_{g,0}^0 \Psi_N^0 \frac{dP}{8\pi^2}
\]
where * stands for equilibrium, that is \( V_g = V_e = V_p = 0 \) in the present approximation) and \( \beta_e = \beta_p = \beta \) (see Appendix).

The equations of order 0 are the starting point of our macroscopic model. By projecting the electron one over 1 the continuity equation for electrons and holes read
\[
\frac{\partial}{\partial t} \int n_{p,a}^0 \frac{dP}{8\pi} + \nu \int n_{e,a}^0 v \otimes dP = 0 \quad (4)
\]

By projecting the electron equation over \( p \) and the phonon ones on \( k \) we get the following balance equations for momentum \( (e_a = e, -e, \alpha = e, h) \):
\[
\frac{\partial}{\partial t} \int n_{p,a}^0 \frac{dP}{8\pi} + \nu \int n_{e,a}^0 v \otimes dP = \int \left( \frac{\partial n_{p,a}^0}{\partial t} \right)_{pp} \frac{dP}{8\pi} + \int \left( \frac{\partial n_{e,a}^0}{\partial t} \right)_{pp} \frac{dP}{8\pi} \quad (5)
\]

\[
\frac{\partial}{\partial t} \int n_{e,a}^0 \frac{dP}{8\pi} + \nu \int n_{e,a}^0 v \otimes dP = \int \left( \frac{\partial n_{e,a}^0}{\partial t} \right)_{pp} \frac{dP}{8\pi} + \int \left( \frac{\partial n_{e,a}^0}{\partial t} \right)_{pp} \frac{dP}{8\pi} \quad (5)
\]

\[
\int N_{e,a}^0 dK + \nu \int n_{e,a}^0 v \otimes dK
\]

\[
\int N_{e,a}^0 dK + \nu \int n_{e,a}^0 v \otimes dK
\]

\[
\int N_{e,a}^0 dK + \nu \int n_{e,a}^0 v \otimes dK
\]
where we took advantage of
\[ \int \left( \frac{\partial N_{pp}}{\partial t} \right)_{pp} \, dp \, dk = 0, \]
due to momentum conservation for N-processes. For the same reason we have
\[ 2 \int \left( \frac{\partial N_{pp}}{\partial t} \right)_{pp} \, dp \, dk = 0, \]
where
\[ \sum_{g} \int \left( \frac{\partial N_{pp}}{\partial t} \right)_{pp} \, dp \, dk = \left( \beta_{p} - \beta_{a} \right) \sum_{g} \int 2 \omega_{p} (P', k \rightarrow P) \psi_{g} \phi_{g} \phi'_{g} \, dp \, dk / 8\pi^{3}. \]
This term is responsible for momentum relaxation.

Finally, by projecting the electron equation over \( \varepsilon_{\ell} \), we get the following balance equations for energy
\[ \sum_{g} \int \left( \frac{\partial n_{a}}{\partial t} \right)_{pp} \, dp \, dk = 2 \left( \beta_{p} - \beta_{a} \right) \sum_{g} \int \omega_{p} (P', k \rightarrow P) \psi_{g} \phi_{g} \phi'_{g} \, dp \, dk / 8\pi^{3}. \]
where we took advantage of
\[ \int \left( \frac{\partial n_{p}}{\partial t} \right)_{pp} \, dp \, dk = 0, \]
due to energy conservation for N-processes. For the same reason we have
\[ 2 \int \left( \frac{\partial n_{p}}{\partial t} \right)_{pp} \, dp \, dk = 0, \]
where
\[ \sum_{g} \int \left( \frac{\partial n_{p}}{\partial t} \right)_{pp} \, dp \, dk = 2 \left( \beta_{p} - \beta_{a} \right) \sum_{g} \int \omega_{p} (P', k \rightarrow P) \psi_{g} \phi_{g} \phi'_{g} \, dp \, dk / 8\pi^{3}. \]
This term, responsible for the thermal relaxation, generalizes the results which can be found in the literature \[6\], by means of the functions “phi” and “psi” we introduced.

Equations (4)-(6) constitute now a closed set of equations for the unknowns \( \mu, \beta_{a}, V_{\alpha}(\alpha = e, p) \) which recall the extended thermodynamical one \[4\].

### 4. Revised Drift-Diffusion Approximation

In the drift-diffusion approximation we assume that the total momentum of the mixture does not vary appreciably
\[ B_{p} = -\frac{1}{2} \sum_{g \neq g_{0}} \int \Phi_{g} \Phi_{g} \phi_{g} \omega_{p} (k_{2}, k_{1} \rightarrow k_{2}) (k_{1} - k_{2} - k_{1}) \phi_{g} \phi'_{g} \, dp \, dk / 8\pi^{3}, \]
and
\[ D_{a} = 2 \sum_{g} \int \omega_{p} (p', k \rightarrow p) \psi_{g} \phi_{g} \phi'_{g} \, dp \, dk / 8\pi^{3}. \]
Moreover
\[ X_{e} = -2 \beta_{p} R_{e} \cdot V_{e} - 2 \beta_{p} R_{e} \cdot E_{e}, \]
where
\[ X_{e} = E + (1/e) \nabla \mu_{e}, \quad E_{e} = E - (1/e) \nabla \mu_{e}, \quad \text{and} \]
\[ R_{e} = \int \frac{\beta_{a}}{\mu_{a}} \left[ T_{e} \left( \varepsilon_{e} - \mu_{e} \right) \right] p \, dp \, \varepsilon \, \ell = 1, 3. \]
\[ R_i = \int \mathcal{F} \left[ \beta_i \left( \varepsilon_i - \mu_i \right) \right] e_i \mathbf{p} \otimes \mathbf{v} \mathbf{p} \]
\[ \alpha = e, h \quad \ell = 2, 4 \]
\[ R_\ell = \sum g \int \mathcal{B}' (\beta, \omega_g) \omega_g \mathbf{u}_g \otimes \mathbf{u}_g \mathbf{d}k, \]
where we can write
\[ R_\ell = r_i I \quad \ell = 1, 3. \]

Since in the present approximation all the moments are calculated by means of drifted (generalized) FD or BE distribution functions, the electrical \( (J_e) \) and thermal \( (\mathbf{u}_t, \mathbf{u}_h) \) currents are given by [8]
\[ J_e = -\frac{e}{4\pi} \int \mathbf{v} \mathbf{u}_e \mathbf{p} \mathcal{F} \left[ \beta \left( \varepsilon_i - \mu_i \right) \right] \mathbf{d}p \]
\[ \mathbf{U}_t = \frac{1}{8\pi} \sum g \int \omega_g \mathbf{u}_g \mathbf{N}_g \mathbf{d}k \]
so that we get finally the following Onsager symmetry relations:
\[ K_{mn} = \bar{K}_{mn} \]
And, in the presence of an external applied field
\[ K_{mn} (-B) = \bar{K}_{mn} (B) \]

5. Conclusions

A new two-fluid model for electron-phonon system has been proposed, which is certainly related to the extended thermodynamical one [4], for the purpose of calculating energy and momentum relaxation rates which generalize the results available in the literature [6]. The treatment resorts here strictly to kinetic theory, so that the model is closed. This means that we do not need adjustment of some free parameters (namely the relaxation times) by means of comparisons with Monte Carlo calculations. A revised drift-diffusion approximation has been derived. An obvious improvement with respect to the classical drift-diffusion model is constituted by the introduction of an energy balance equation. The fulfillment of the symmetry Onsager relations is not trivial, since it cannot taken for granted in many macroscopic models.

A further step, for future work, could be the introduction of holes and photons in the model, in order to account for generation-recombination effects.

REFERENCES

Consider the equations at order –1:

\[
\left( \frac{\partial N_g}{\partial t} \right)_{pp}^{NN} = 0, \quad \left( \frac{\partial n_p}{\partial t} \right)_{we}^{NN} = 0, \quad \left( \frac{\partial n_k}{\partial t} \right)_{pp}^{NN} = 0.
\]

By means of the usual methods of kinetic theory it can be shown that these conditions are equivalent to

\[
\Phi_s^N \Phi_s^N \Phi_s^N = \Phi_s^N \Phi_s^N \Phi_s^N, \quad \forall k, k_i \quad (A1)
\]

\[
\psi^{\alpha_N} \psi^{\alpha_N} \psi^{\alpha_N} = \psi^{\alpha_N} \psi^{\alpha_N} \psi^{\alpha_N}, \quad \forall p, p_i \quad (A2)
\]

Condition (A1) shows that \( \ln(\Phi_s^N / \psi_s^N) \) is a collisional invariant for phonons. In the case of N-processes

\[
\ln(\Phi_s^N / \psi_s^N) = \left( V_p \cdot k - \omega_g \right) / T_p.
\]

Condition (A2) shows that \( \ln(\psi_s^{\alpha_N} / \psi_s^{\alpha_N}) \) is a collisional invariant for electrons. In the case of N-processes

\[
\ln(\psi_s^{\alpha_N} / \psi_s^{\alpha_N}) = \left( V_e \cdot k - \varepsilon_p + \mu \right) / T_e.
\]

On the other hand the equilibrium condition for ep interactions reads

\[
\psi_s^{\alpha_N} \psi_s^{\alpha_N} \psi_s^{\alpha_N} = \psi_s^{\alpha_N} \psi_s^{\alpha_N} \Phi_s^N, \quad \forall p, k
\]

which give

\[
\left( \beta_a V_a - \beta_p V_p \right) \cdot k + \omega_g \left( \beta_p - \beta_a \right) = 0
\]

or, since \( \omega_g \) is even

\[
-\left( \beta_a V_a - \beta_p V_p \right) \cdot k + \omega_g \left( \beta_p - \beta_a \right) = 0
\]

\[
V_e = V_h = V_p, \quad \beta_e = \beta_h = \beta_p.
\]

\[\text{Appendix 2}\]

Rewrite the equations as

\[
A_{xe} \cdot \hat{V} + A_{xp} \cdot \hat{V}_p = X_e
\]

\[
A_{pe} \cdot \hat{V}_e + A_{ph} \cdot \hat{V}_h + A_{pp} \cdot \hat{V}_p = X_p
\]

\[
A_{eh} \cdot \hat{V}_h + A_{hp} \cdot \hat{V}_p = X_h,
\]

which give

\[
\hat{V}_e = A_{xe}^{-1} \left( X_e - A_{xp} \cdot \hat{V}_p \right)
\]

\[
\hat{V}_h = A_{eh}^{-1} \left( X_h - A_{hp} \cdot \hat{V}_p \right)
\]

and

\[
A_{pe} \cdot A_{xe}^{-1} \left( X_e - A_{xp} \cdot \hat{V}_p \right) + A_{ph} \cdot A_{eh}^{-1} \left( X_h - A_{hp} \cdot \hat{V}_p \right)
\]

so that we get finally the following Onsager symmetry relations:

\[
K_{mn} = K_{nm}.
\]

And, in the presence of and external applied field

\[
K_{mn} (B) = K_{mn} (B)
\]

since

\[
R_e = r_I B, \quad \ell = 1, 3.
\]